MOSFET – Power, Single, N-Channel 100 V, 8 mΩ, 104 A

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
100 V	8 mΩ @ 10 V	104 A

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Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	100	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain		T _C = 25°C	۱ _D	104	А
Current R _{θJC} (Notes 1, 2, 3)	Steady	T _C = 100°C		66	
Power Dissipation	State	$T_{C} = 25^{\circ}C$	PD	138	W
$R_{\theta JC}$ (Notes 1, 2)		$T_{C} = 100^{\circ}C$		56	
Continuous Drain		T _A = 25°C	۱ _D	16	А
Current R _{θJA} (Notes 1, 2, 3)	Steady	$T_A = 100^{\circ}C$		10	
Power Dissipation $R_{\theta JA}$ (Notes 1 & 2)	State	T _A = 25°C	PD	3.3	W
		T _A = 100°C		1.3	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	370	А
Operating Junction and Storage Temperature			T _J , T _{stg}	–55 to + 150	°C
Source Current (Body Diode)			I _S	130	А
Single Pulse Drain-to-Source Avalanche Energy ($I_{L(pk)} = 50 \text{ A}$)			E _{AS}	125	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C
Stresses exceeding those	e listed in t	he Maximum R	atings table	mav dam	age the

 MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

 Parameter
 Symbol

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

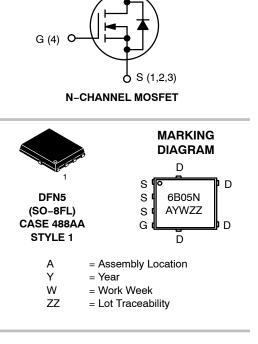
THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	0.9	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

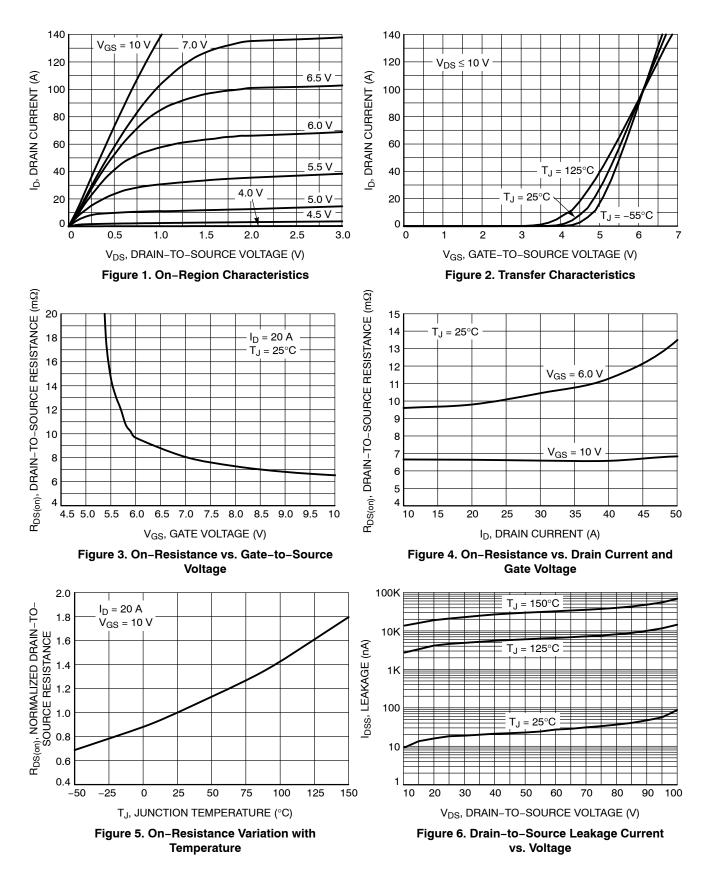
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		100			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / TJ				73		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V,$	T _J = 25 °C			10	
		V _{DS} = 80 V T _J = 125°C				100	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$		2.0		4.0	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J	1			-7.9		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A		6.5	8.0	mΩ
		V _{GS} = 6.0 V	I _D = 10 A		9.6	14	
CHARGES, CAPACITANCES & GATE RE	SISTANCE			-			
Input Capacitance	C _{ISS}			3100		pF	
Output Capacitance	C _{OSS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 50 V			570		
Reverse Transfer Capacitance	C _{RSS}				28		
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 10 \text{ V}, \text{ V}_{DS} = 50 \text{ V}; \text{ I}_{D} = 25 \text{ A}$ $T_{J} = 25 \text{ °C}$			44		nC
Threshold Gate Charge	Q _{G(TH)}				5.0		
Gate-to-Source Charge	Q _{GS}				14		
Gate-to-Drain Charge	Q _{GD}				12		
Plateau Voltage	V _{GP}				5.0		V
Gate Resistance	R _G				1.0		Ω
SWITCHING CHARACTERISTICS (Note 5	5)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V_{DS} = 50 V, I _D = 25 A, R _G = 1.0 Ω			14		- ns
Rise Time	tr				43		
Turn-Off Delay Time	t _{d(OFF)}				39		
Fall Time	t _f				16		
DRAIN-SOURCE DIODE CHARACTERIS	TICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.9	1.2	2 V
		I _S = 25 A	T _J = 125°C		0.8		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dl _S /d _t = 100 A/μs, I _S = 25 A			58		
Charge Time	t _a				30		ns
Discharge Time	t _b				28		
Reverse Recovery Charge	Q _{RR}				83		nC

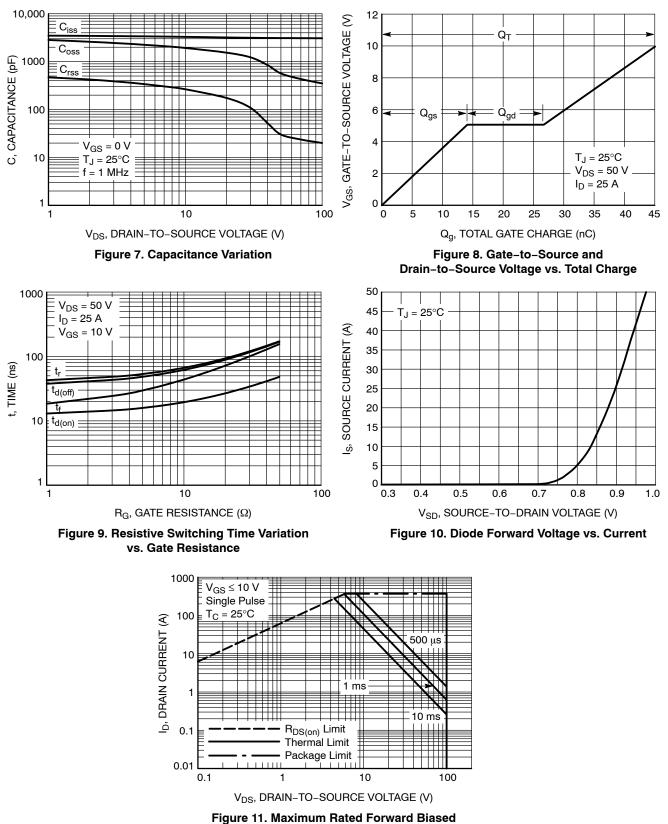
Produ parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

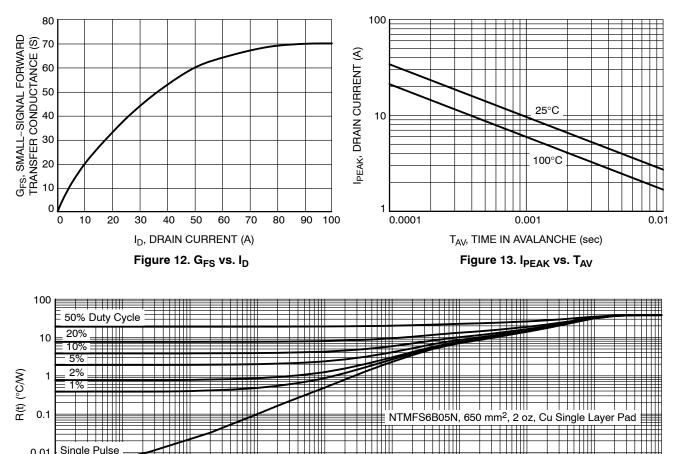


TYPICAL CHARACTERISTICS



Safe Operating Area

TYPICAL CHARACTERISTICS





0.001

DEVICE ORDERING INFORMATION

0.000001 0.00001 0.0001

Single Pulse

0.01

0.001

Device	Marking	Package	Shipping [†]
NTMFS6B05NT1G	6B05N	DFN5 (Pb-Free)	1500 / Tape & Reel
NTMFS6B05NT3G	6B05N	DFN5 (Pb–Free)	5000 / Tape & Reel

0.01

0.1

1

10

+

100

1000

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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